

# **SNS COLLEGE OF TECHNOLOGY An Autonomous Institution Coimbatore-35**

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# **DEPARTMENT OF ELECTRONICS & COMMUNICATION ENGINEERING 19ECB311- OPTICAL AND MICROWAVE ENGINEERING**

III YEAR/ VI SEMESTER

**UNIT II-MICROWAVE ACTIVE DEVICES** 

**TOPIC 3-PIN DIODE** 

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4/28/2023





# Guess the TOPIC







# **CONTENTS**

- **\***Introduction
- Symbol and construction of Pin Diode
- Working of Pin diode.
- **\***Applications
- **References**









# PIN Diode

# Wide un-doped intrinsic semiconductor region

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# **Pin diode-symbol**



Wide intrinsic region in contrast to an ordinary p-n diode

P type and N type regions are heavily doped





# **Pin diode-Working Principle**

## P and N regions are heavily doped because they are used for Ohmic contacts







## **PIN DIODE-EQUIVALENT CIRCUIT**





Large stored charge adrift in a thick intrinsic region



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# Used in RF and Microwave



# CHARACTERISTICS



## **PIN Diode IV Curve**

## Used in RF and Microwave variable attenuator

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*High reverse breakdown voltage:* The width of the depletion layer in PIN diode is large. It imparts it the ability of high reverse breakdown voltage. Thus, it is suitable for • protection of circuits from a large current. •*High Capacitance:* The width of intrinsic layer is large due to which capacitance of diode is low. As the capacitance of a device is inversely proportional to the distance between the electrodes. **Photodetection:** Due to the large width of the intrinsic layer, the photons striking the • surface will be more. And the generation of the electron-hole pair will also increase. Due to which more current will flow. Thus, PIN diode helps to achieve improved photo-• detection.





DISADVANTAGES

# *High Reverse Recovery Time:* The PIN diode has high reverse recovery time due to which power losses are significant.











## **1.An RF Microwave PIN diode Attenuator.** 2.A PIN Diode RF Microwave Switch. **3.Photodetector and photovoltaic cell 4.Limiter PIN diodes are useful as RF switches, attenuators, photodetectors, and phase shifters**







# **THANK YOU**

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